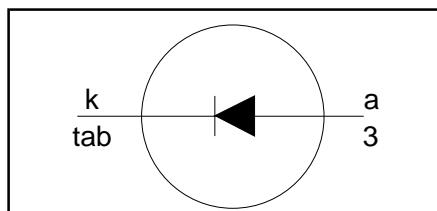


Rectifier diodes
Schottky barrier
PBYR1045D series
FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL

QUICK REFERENCE DATA

$$V_R = 40 \text{ V} / 45 \text{ V}$$

$$I_{F(AV)} = 10 \text{ A}$$

$$V_F \leq 0.57 \text{ V}$$

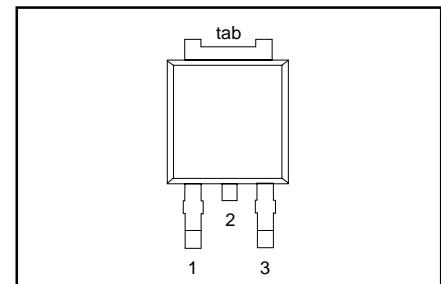
GENERAL DESCRIPTION

Schottky rectifier diodes in a plastic envelope. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR1045D series is supplied in the surface mounting SOT428 package.

PINNING

PIN	DESCRIPTION
1	no connection
2	cathode ¹
3	anode
tab	cathode

SOT428

LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V_{RRM}	Peak repetitive reverse voltage	PBYR10	-	40D	45D	V
V_{RWM}	Working peak reverse voltage		-	40	45	V
V_R	Continuous reverse voltage	$T_{mb} \leq 113 \text{ }^\circ\text{C}$	-	40	45	V
$I_{F(AV)}$	Average rectified forward current	square wave; $\delta = 0.5$; $T_{mb} \leq 134 \text{ }^\circ\text{C}$	-	10		A
I_{FRM}	Repetitive peak forward current	square wave; $\delta = 0.5$; $T_{mb} \leq 134 \text{ }^\circ\text{C}$	-	20		A
I_{FSM}	Non-repetitive peak forward current	$t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ sinusoidal; $T_j = 125 \text{ }^\circ\text{C}$ prior to surge; with reapply $V_{RRM(max)}$ pulse width and repetition rate limited by $T_{j max}$	-	100	110	A
I_{RRM}	Peak repetitive reverse surge current		-	1		A
T_j	Operating junction temperature		-	150		$^\circ\text{C}$
T_{stg}	Storage temperature		- 65	175		$^\circ\text{C}$

¹ It is not possible to make connection to pin 2 of the SOT428 package.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j\cdot mb}$	Thermal resistance junction to mounting base		-	-	2	K/W
$R_{th\ j\cdot a}$	Thermal resistance junction to ambient	pcb mounted, minimum footprint, FR4 board	-	50	-	K/W

ELECTRICAL CHARACTERISTICS

$T_j = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 10\text{ A}; T_j = 125^\circ\text{C}$ $I_F = 20\text{ A}; T_j = 125^\circ\text{C}$ $I_F = 20\text{ A}$	-	0.5	0.57	V
I_R	Reverse current	$V_R = V_{RWM}$ $V_R = V_{RWM}; T_j = 100^\circ\text{C}$	-	0.74	0.8	V
C_d	Junction capacitance	$V_R = 5\text{ V}; f = 1\text{ MHz}, T_j = 25^\circ\text{C to } 125^\circ\text{C}$	-	0.65	0.84	V
			-	0.2	1.3	mA
			-	22	35	mA
			-	350	-	pF

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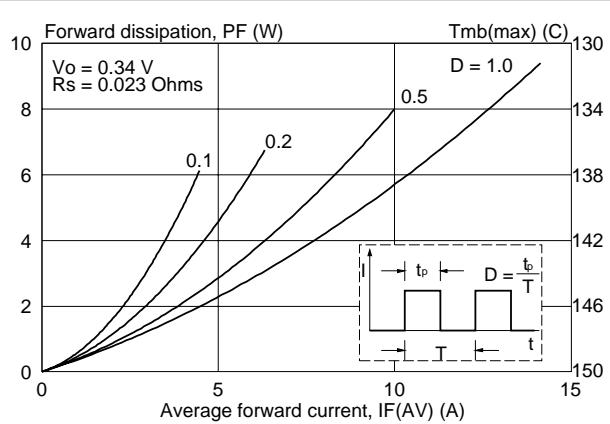


Fig.1. Maximum forward dissipation $P_F = f(I_{F(AV)})$;
square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$.

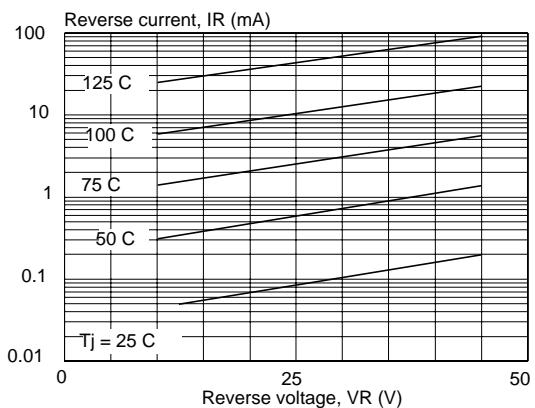


Fig.4. Typical reverse leakage current; $I_R = f(V_R)$;
parameter T_j

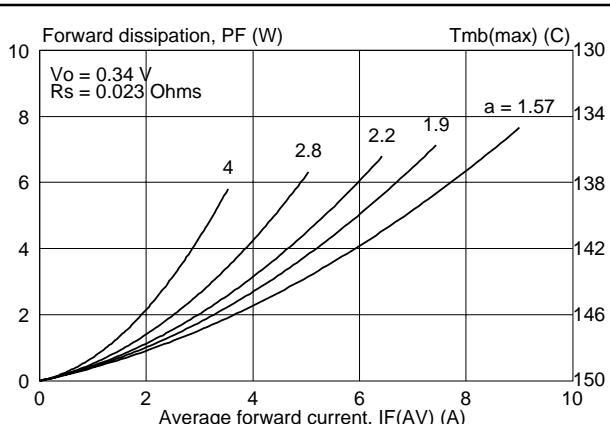


Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)})$;
sinusoidal current waveform where $a = \text{form}$
 $\text{factor} = I_{F(RMS)} / I_{F(AV)}$.

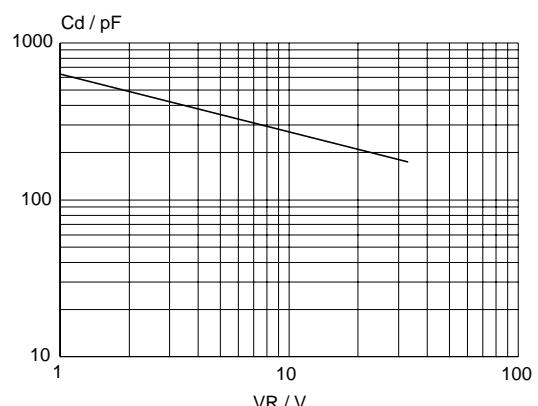


Fig.5. Typical junction capacitance; $C_d = f(V_R)$;
 $f = 1 \text{ MHz}$; $T_j = 25^\circ\text{C}$ to 125°C .

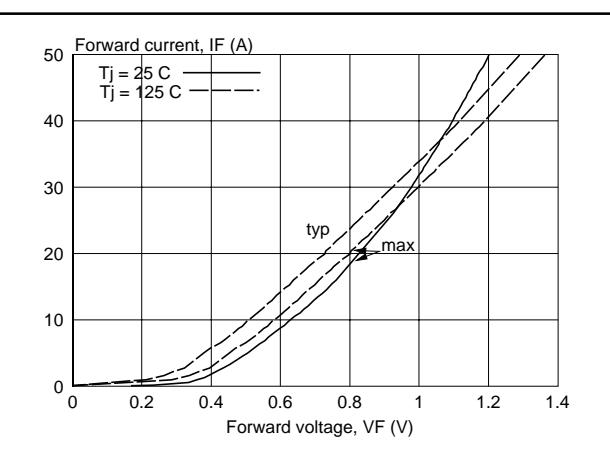


Fig.3. Typical and maximum forward characteristic
 $I_F = f(V_F)$; parameter T_j

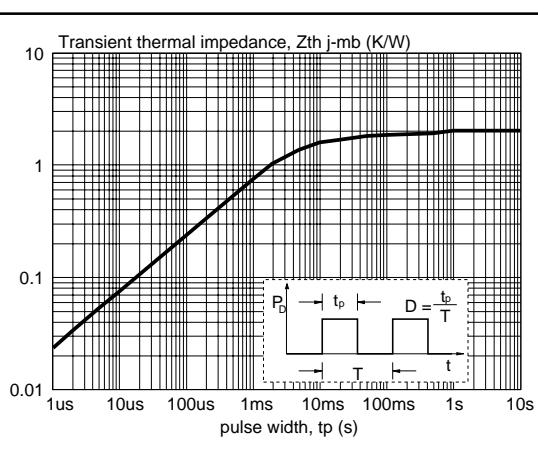


Fig.6. Transient thermal impedance; $Z_{th,j-mb} = f(t_p)$.

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MECHANICAL DATA

Dimensions in mm : Net Mass: 1.4 g

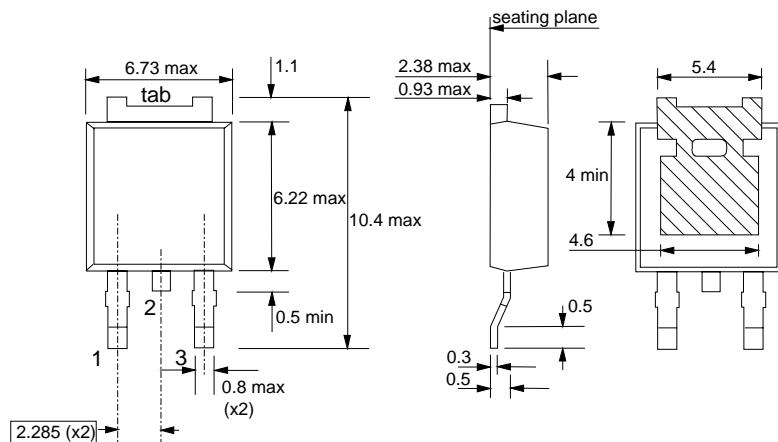


Fig.7. SOT428 : centre pin connected to mounting base.

MOUNTING INSTRUCTIONS

Dimensions in mm

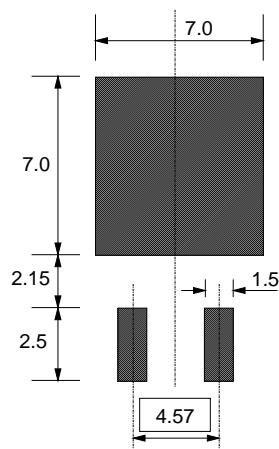


Fig.8. SOT428 : soldering pattern for surface mounting.

Notes

1. Observe the general handling precautions for electrostatic-discharge sensitive devices (ESDs) to prevent damage to MOS gate oxide.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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